

Submission Deadline: Sep.10,2017

=Conference Venue=

Southeast University, Nanjing, CHINA

Sipailou 2#, Nanjing, Jiangsu Province, 210096 P. R. China

ABOUT

ICICM 2016 proceedings have been indexed by EI COMPENDEX and SCOPUS, CPCI (Web of Science).

All accepted papers after proper presentation and registration will be collected in the conference proceedings, which will be submitted and reviewed in the IEEE Xplore, Ei Compendex, and Scopus

CONFERENCE SCOPE

Digital, Analog, Mixed Signal IC and SOC design technology Silicon integrated circuits and manufacturing

Low-power, RF devices & circuits

IC Computer-Aided –Design technology, DFM

Silicon/germanium devices and device physics

Interconnect, Low K, High K and other process technologies

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Unconventional and nano-electronics

Organic semiconductor devices and technologies

Compound semiconductor devices and circuits

Displays, sensors and MEMS

Semiconductor materials and material characterization

Packaging and testing technology

Solar cell & other devices for new energy sources

Modeling and simulation

Equipment technolog

Reliability

Displays, sensors and MEMS

Advance memories technology (Flash, FeRAM,

PCM, ReRAM, MRAM etc.)

KEYNOTE

- *Prof. Qiang Li
- --University of Electronic Science and

Technology of China, China

- *Prof. Gene Eu (Ching Yuh) Jan
- --National Taipei University, Taiwan
- *Prof. Xiaoxiao Wang
- --BeiHang University, China
- *Prof. Dai Yong-Sheng
- -- Nanjing University of Science & Technology, China

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